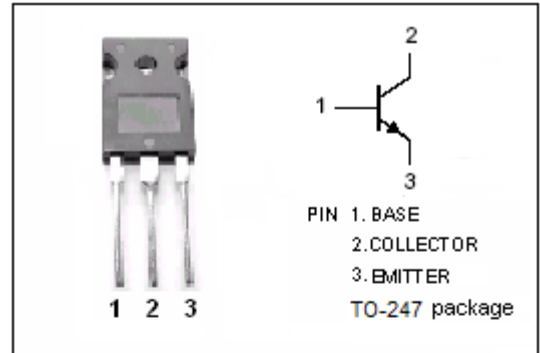


**DESCRIPTION**

- High Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(SUS)} = 450V(\text{Min})$
- High Switching Speed
- High Reliability

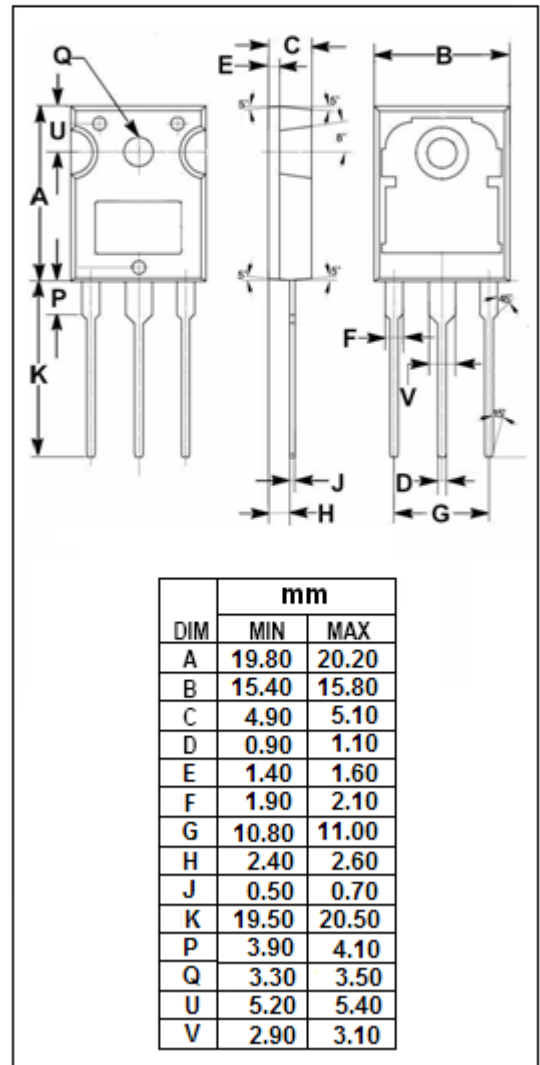
**APPLICATIONS**

- Designed for switching regulator and general purpose applications.



**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

| SYMBOL    | PARAMETER                              | VALUE   | UNIT |
|-----------|--|---------|------|
| $V_{CBO}$ | Collector-Base Voltage                 | 600     | V    |
| $V_{CEO}$ | Collector-Emitter Voltage              | 450     | V    |
| $V_{EBO}$ | Emitter-Base voltage                   | 7       | V    |
| $I_C$     | Collector Current-Continuous           | 20      | A    |
| $I_{CM}$  | Collector Current-Peak                 | 40      | A    |
| $I_B$     | Base Current-Continuous                | 7       | A    |
| $I_{BM}$  | Base Current-Peak                      | 14      | A    |
| $P_C$     | Collector Power Dissipation @ $T_C=25$ | 150     | W    |
| $T_J$     | Junction Temperature                   | 150     |      |
| $T_{stg}$ | Storage Temperature Range              | -55~150 |      |



**THERMAL CHARACTERISTICS**

| SYMBOL        | PARAMETER                            | MAX  | UNIT |
|---------------|--------------------------------------|------|------|
| $R_{th\ j-c}$ | Thermal Resistance, Junction to Case | 0.83 | /W   |

**Silicon NPN Power Transistor**

**2SC4060**

**ELECTRICAL CHARACTERISTICS**

$T_C=25$  unless otherwise specified

| SYMBOL         | PARAMETER                            | CONDITIONS             | MIN | TYP. | MAX | UNIT |
|----------------|--------------------------------------|------------------------|-----|------|-----|------|
| $V_{CEQ(SUS)}$ | Collector-Emitter Sustaining Voltage | $I_C= 0.2A; I_B= 0$    | 450 |      |     | V    |
| $V_{CE(sat)}$  | Collector-Emitter Saturation Voltage | $I_C= 10A; I_B= 2A$    |     |      | 1.0 | V    |
| $V_{BE(sat)}$  | Base-Emitter Saturation Voltage      | $I_C= 10A; I_B= 2A$    |     |      | 1.5 | V    |
| $I_{CBO}$      | Collector Cutoff Current             | $V_{CB}= 600V; I_E= 0$ |     |      | 0.1 | mA   |
| $I_{CEO}$      | Collector Cutoff Current             | $V_{CE}= 450V; I_B= 0$ |     |      | 0.1 | mA   |
| $I_{EBO}$      | Emitter Cutoff Current               | $V_{EB}= 7V; I_C= 0$   |     |      | 0.1 | mA   |
| $h_{FE-1}$     | DC Current Gain                      | $I_C= 10A; V_{CE}= 5V$ | 10  |      |     |      |
| $h_{FE-2}$     | DC Current Gain                      | $I_C= 1mA; V_{CE}= 5V$ | 5   |      |     |      |
| $f_T$          | Current-Gain—Bandwidth Product       | $I_C= 2A; V_{CE}= 10V$ |     | 20   |     | MHz  |

Switching Times

|           |              |  |  |  |     |         |
|-----------|--------------|--|--|--|-----|---------|
| $t_{on}$  | Turn-on Time | $I_C= 10A, I_{B1}= 2A; I_{B2}= -4A$<br>$R_L= 15 \Omega; V_{BB2}= 4V$ |  |  | 0.5 | $\mu s$ |
| $t_{stg}$ | Storage Time |  |  |  | 2.0 | $\mu s$ |
| $t_f$     | Fall Time    |  |  |  | 0.2 | $\mu s$ |